

# FB330M ~ FB340M

# SURFACE MOUNT SCHOTTKY BARRIER RECTIFIER

## REVERSE VOLTAGE – 40Volts FORWARD CURRENT – 3.0 Ampere

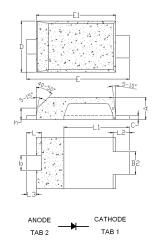
#### **FEATURES**

- Very low profile package 0.80mm
- · High efficiency
- · Low forward voltage drop, low power loss
- For use in low voltage, high frequency inverters, free wheeling, dc-to-dc converters and polarity protection applications
- ESD Capability: Machine Model, C (> 400 V) Human Body Model, 3B ( > 8 kV)

#### **MECHANICAL DATA**

- Case: JEDEC DO-222AA
- Case Material: "Green" molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl.)
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Lead Free Plating (Matte Tin Finish.)
- · Reliability tested in accordance with AEC-Q101
- Component in accordance to RoHs 2002/95/EC

### Mite Flat



| DO-222AA                    |      |      |  |  |  |
|-----------------------------|------|------|--|--|--|
| DIM.                        | MIN. | MAX. |  |  |  |
| Α                           | 0.80 | 0.95 |  |  |  |
| b                           | 0.40 | 0.65 |  |  |  |
| b2                          | 0.70 | 1.00 |  |  |  |
| С                           | 0.10 | 0.25 |  |  |  |
| D                           | 1.75 | 2.05 |  |  |  |
| Е                           | 3.60 | 3.90 |  |  |  |
| E1                          | 2.80 | 3.10 |  |  |  |
| h                           | 0.35 | 0.50 |  |  |  |
| L                           | 0.50 | 0.80 |  |  |  |
| L1                          | 2.10 | 2.60 |  |  |  |
| L2                          | 0.45 | 0.75 |  |  |  |
| L3                          | 0.20 | 0.50 |  |  |  |
| All Dimension in millimeter |      |      |  |  |  |

#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

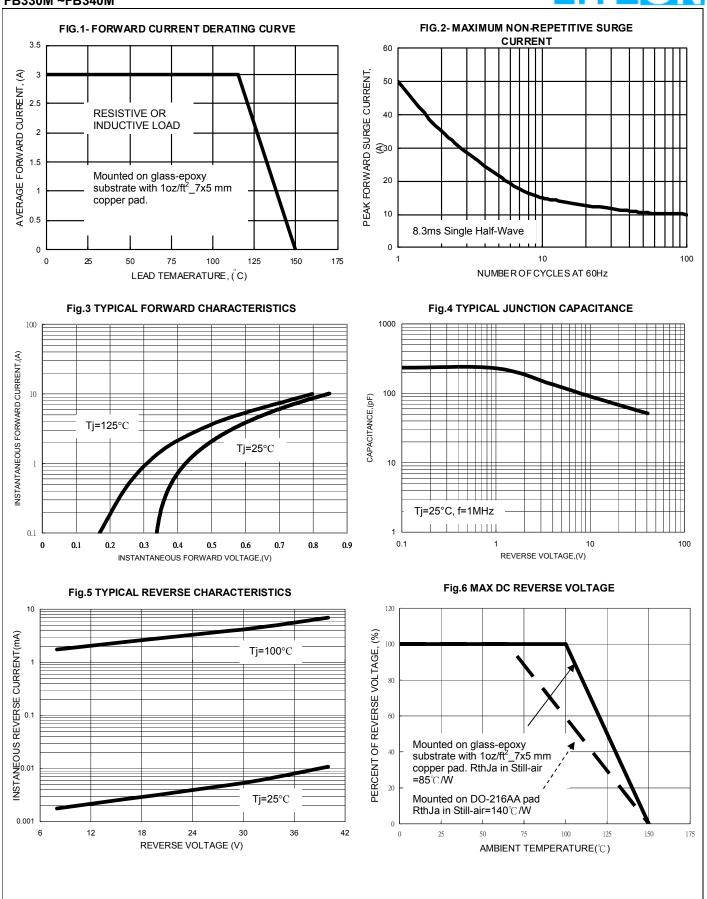
| PARAMETER   |           |                     | SYMBOL            | FB330M       | FB340M       | UNIT      |
|---|-----------|---------------------|-------------------|--------------|--------------|-----------|
| Device marking code   |           |                     | Note              | B33          | B34          |           |
| Maximum Repetitive Peak Reverse Voltage                         |           |                     | $V_{RRM}$         | 30           | 40           | V         |
| Maximum RMS Voltage   |           |                     | V <sub>RMS</sub>  | 21           | 28           | V         |
| Maximum DC Blocking Voltage                                     |           |                     | $V_{DC}$          | 30           | 40           | V         |
| Average Rectified Output Current @T <sub>L</sub> =115°C,(Fig.1) |           |                     | I <sub>(AV)</sub> | 3.0          |              | А         |
| Peak Forward Surge Current 8.3ms single half sine-wave          |           | I <sub>FSM</sub>    | 50                |              | Α            |           |
| Operating junction and storage temperature range                |           | $T_{STG},T_{J}$     | -55 to +150       |              | °C           |           |
| PARAMETER   | TEST CO   | TEST CONDITIONS     |                   | Тур.         | Max.         | UNIT      |
| Forward Voltage (1)   | IF=3.0A   | Tj=25°C<br>Tj=125°C | V <sub>F</sub>    | 0.52<br>0.45 | 0.58<br>0.48 | V         |
| Leakage Current (1)   | VDC=Rated | Tj=25°C<br>Tj=100°C | I <sub>R</sub>    |              | 200<br>15    | uA<br>mA  |
| THERMAL CHARACTERISTIC  |           | SYMBOL              | Typical           |              | UNIT         |           |
| Typical junction capacitance (2)                                |           | CJ                  | 135               |              | pF           |           |
| Typical thermal resistance_Junction to Case (3)                 |           | R⊖ <sub>JC</sub>    | 15                |              | °C/W         |           |
| Typical thermal resistance_Junction to Ambient(3)               |           | R⊖ <sub>JA</sub>    | 85                |              | °C/W         |           |
| Typical thermal resistance_Junction to Lead (3)                 |           |                     | R⊖JL              | 20           |              | °C/W      |
| Note:   |           |                     |                   |              |              | 12 KCHD04 |

#### Note:

REV.5, Mar-2012, KSHP01

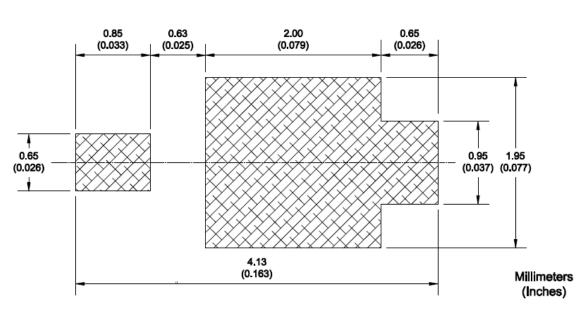
- 1) 300us Pulse width, 2% Duty cycle.
- 2) Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
- (3) Thermal Resistance test performed in accordance with JESD-51. Unit mounted on glass-epoxy substrate with 1oz/ft²\_7x5 mm copper pad. R<sub>eJL</sub> is measured at the lead of cathode band, R<sub>eJC</sub> is measured at the top centre of body, R<sub>eJa</sub> is measured at top surface of the package to surrounding natural convection (Still air) ambient.













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